





### **100V NPN DARLINGTON TRANSISTOR IN SOT223**

#### **Features**

- BV<sub>CEO</sub> > 100V
- BV<sub>CBO</sub> > 100V
- I<sub>C</sub> = 1.5A high Continuous current
- hFE > 10k for very high gain @ 100mA
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

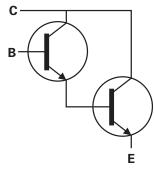
- Case: SOT223
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (approximate)

## **Applications**

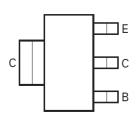
- Lamp
- Relay
- Solenoid driving







Device Symbol



Top View Pin-Out

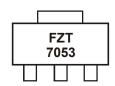
## Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT7053TA	FZT7053	7	12	1,000

Notes

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

## **Marking Information**



FZT7053 = Product Type Marking Code





## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	100	V
Collector-Emitter Voltage	$V_{CEO}$	100	V
Emitter-Base Voltage	$V_{EBO}$	12	V
Continuous Collector Current	Ic	1.5	Α
Peak Pulse Current	I <sub>CM</sub>	2	Α

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P <sub>D</sub>	1	W
Power Dissipation (Note 6)	P <sub>D</sub>	1.25	W
Power Dissipation (Note 7)	P <sub>D</sub>	2	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ heta JA}$	125	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ heta JA}$	100	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	$R_{ heta JA}$	62	°C/W
Thermal Resistance, Junction to Lead (Note 8)	$R_{ heta JL}$	19.4	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes:

- 5. For a device surface mounted on 15mm x 14mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

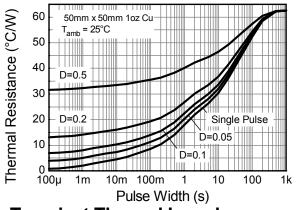
  6. Same as note (5), except the device is surface mounted on 25mm x 25mm with 1oz copper.

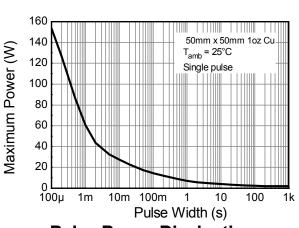
  7. Same as note (5), except the device is surface mounted on 50mm x 50mm with 1oz copper.

  8. Thermal resistance from junction to solder-point (at the end of the collector lead).



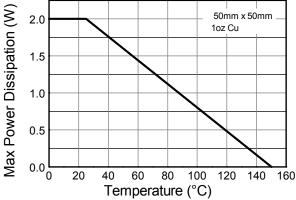
# **Thermal Characteristics and Derating Information**





# **Transient Thermal Impedance**

**Pulse Power Dissipation** 



**Derating Curve** 





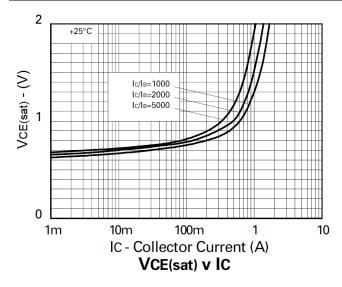
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

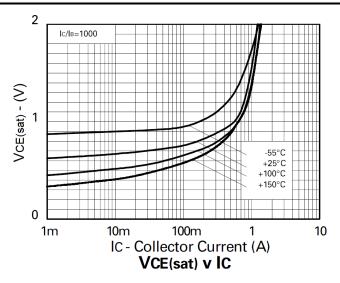
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	100	300	-	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	100	130	-	V	I <sub>C</sub> = 1mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	12	14	-	V	I <sub>E</sub> = 100μA
Collector-Base Cutoff Current	I <sub>CBO</sub>	-	<10	100	nA	V <sub>CB</sub> = 80V
Collector-Emitter Cutoff Current	I <sub>CES</sub>	-	<10	200	nA	V <sub>CE</sub> = 80V
Emitter Cutoff Current	I <sub>EBO</sub>	-	<10	100	nA	V <sub>EB</sub> = 7V
DC Current Gain (Note 9)	h <sub>FE</sub>	10,000 1,000	-	-	-	$I_C = 100 \text{mA}, V_{CE} = 5 \text{V}$ $I_C = 1 \text{A}, V_{CE} = 5 \text{V}$
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	-	-	1.5	V	I <sub>C</sub> = 100mA, I <sub>B</sub> = 0.1mA
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(on)</sub>	-	-	2.0	V	I <sub>C</sub> = 100mA, V <sub>CE</sub> = 5V
Output Capacitance (Note 9)	C <sub>obo</sub>	-	6.0	8.0	pF	V <sub>CB</sub> = 10V. f = 1MHz
Current Gain-Bandwidth Product (Note 9)	f <sub>T</sub>	200	-	-	MHz	V <sub>CE</sub> = 5V, I <sub>C</sub> = 100mA
Turn-On Time	t <sub>on</sub>	-	0.7	-	μs	V <sub>CC</sub> = 10V, I <sub>C</sub> = 100μA
Turn-Off Time	t <sub>off</sub>	-	2.5	-	μs	$I_{B1} = -I_{B2} = 0.1 \text{mA}$

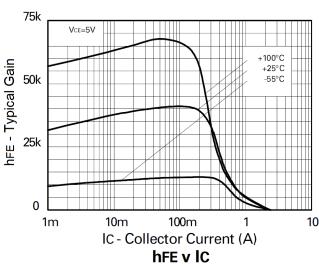
Notes: 9. Measured under pulsed conditions. Pulse width  $\leq$  300  $\mu$ s. Duty cycle  $\leq$  2%.

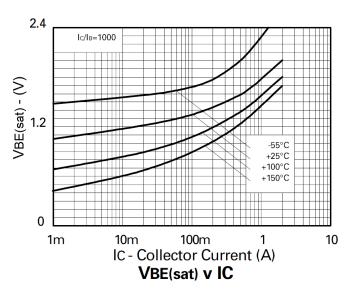


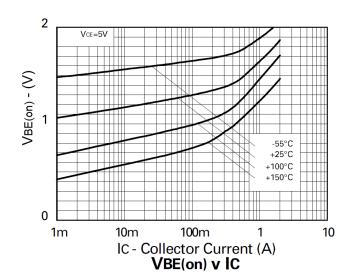
# Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)







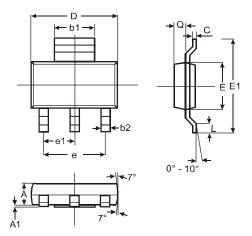






**Package Outline Dimensions** 

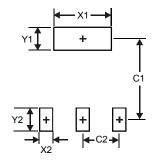
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b1	2.90	3.10	3.00		
b2	0.60	0.80	0.70		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е		_	4.60		
e1		_	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3





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